



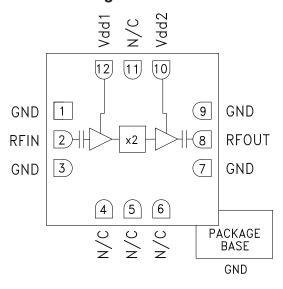
SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 23 - 33 GHz

Typical Applications

The HMC578LC3B is suitable for:

- Clock Generation Applications:
 SONET OC-192 & SDH STM-64
- Point-to-Point & VSAT Radios
- Test Instrumentation
- Military & Space

Functional Diagram



Features

High Output Power: +15 dBm

Low Input Power Drive: 0 to +6 dBm
Fo Isolation: >20 dBc @ Fout= 28 GHz
100 KHz SSB Phase Noise: -132 dBc/Hz

Single Supply: +5V@ 81 mA

RoHS Compliant 3x3 mm SMT Package

General Description

The HMC578LC3B is a x2 active broadband frequency multiplier utilizing GaAs PHEMT technology in a leadless RoHS compliant SMT package. When driven by a +3 dBm signal, the multiplier provides +15 dBm typical output power from 23 to 33 GHz. The Fo and 3Fo isolations are >20 dBc and >30 dBc respectively at 28 GHz. The HMC578LC3B is ideal for use in LO multiplier chains for Pt-to-Pt & VSAT Radios yielding reduced parts count vs. traditional approaches. The low additive SSB Phase Noise of -129 dBc/Hz at 100 kHz offset helps maintain good system noise performance. The RoHS packaged HMC578LC3B eliminates the need for wire bonding, and allows the use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vdd1, Vdd2 = +5V, 3 dBm Drive Level

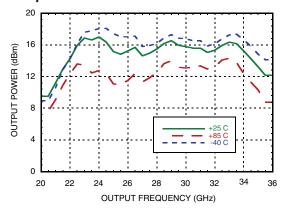
Parameter	Min.	Тур.	Max.	Units
Frequency Range, Input	11.5 - 16.5		GHz	
Frequency Range, Output	23 - 33		GHz	
Output Power	10	15		dBm
Fo Isolation (with respect to output level)		20		dBc
3Fo Isolation (with respect to output level)		30		dBc
Input Return Loss		10		dB
Output Return Loss		12		dB
SSB Phase Noise (100 kHz Offset)		-132		dBc/Hz
Supply Current (Idd1 & Idd2)		81		mA



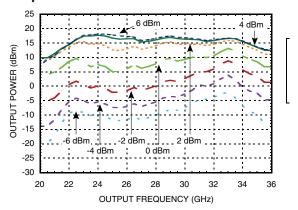


SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 23 - 33 GHz

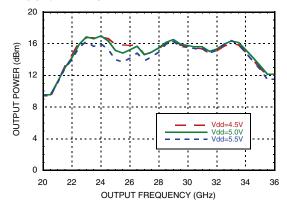
Output Power vs. Temperature @ 3 dBm Drive Level



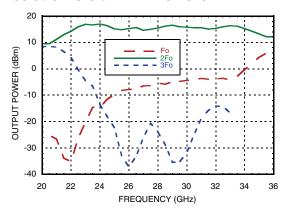
Output Power vs. Drive Level



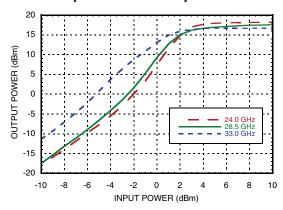
Output Power vs. Supply Voltage @ 3 dBm Drive Level



Isolation @ 3 dBm Drive Level



Output Power vs. Input Power

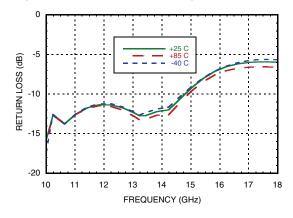




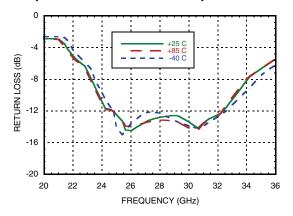


SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 23 - 33 GHz

Input Return Loss vs. Temperature



Output Return Loss vs. Temperature







SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 23 - 33 GHz

Absolute Maximum Ratings

RF Input (Vdd = +5V)	+13 dBm
Supply Voltage (Vdd)	+6.0 Vdc
Channel Temperature	175 °C
Continuous Pdiss (T= 85 °C) (derate 7.4 mW/°C above 85 °C)	670 mW
Thermal Resistance (channel to ground paddle)	135 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

Typical Supply Current vs. Vdd

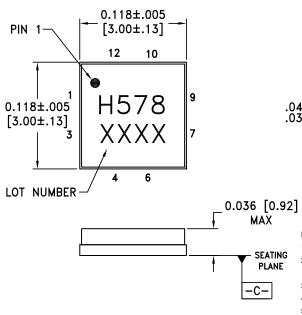
Vdd (Vdc)	Idd (mA)
4.5	81
5.0	81
5.5	81

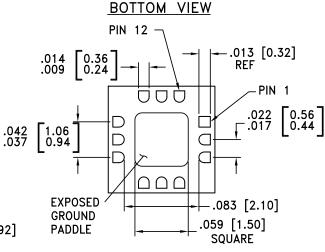
Note:

Multiplier will operate over full voltage range shown above.



Outline Drawing





NOTES:

- 1. PACKAGE BODY MATERIAL: ALUMINA
- 2. LEAD AND GROUND PADDLE PLATING: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKEL.
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM -C-
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC578LC3B	Alumina, White	Gold over Nickel	MSL3 ^[1]	H578 XXXX

^[1] Max peak reflow temperature of 260 $^{\circ}\text{C}$

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

^{[2] 4-}Digit lot number XXXX





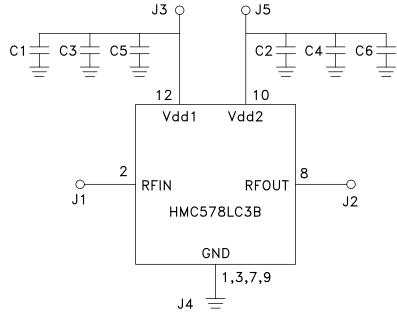
SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 23 - 33 GHz

Pin Description

Pin Number	Function	Description	Interface Schematic
1, 3, 7, 9	GND	Package bottom must also be connected to RF/DC ground.	GND =
2	RFIN	Pin is AC coupled and matched to 50 Ohms.	RFIN ○── ├──
4 - 6, 11	N/C	These pins are internally not connected; however, this product was specified with these pins connected to RF/ DC ground.	
8	RFOUT	Pin is AC coupled and matched to 50 Ohms.	— ├─○ RFOUT
10, 12	Vdd2, Vdd1	Supply voltage 5V ± 0.5V. External bypass capacitors of 100 pF, 1,000 pF and 2.2 μF are required.	Vdd1, Vdd2

Application Circuit

Component	Value
C1, C2	100 pF
C3, C4	1,000 pF
C5, C6	2.2 µF

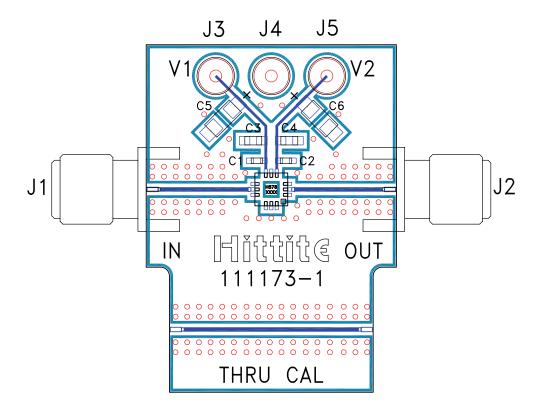






SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 23 - 33 GHz

Evaluation PCB



List of Materials for Evaluation PCB 112409 [1]

Item	Description
J1, J2	PCB Mount SRI K Connector
J3 - J5	DC Pin
C1, C2	100 pF Capacitor, 0402 Pkg.
C3, C4	1,000 pF Capacitor, 0603 Pkg.
C5, C6	2.2 µF Tantalum Capacitor
U1	HMC578LC3B x2 Active Multiplier
PCB [2]	111173 Eval Board

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Rogers 4350